

L Number	Hits	Search Text	DB	Time stamp
17	789	porous with thermal adj conductivity	USPAT; US-PGPUB	2003/09/28 13:27
18	6	porous with thermal adj conductivity with SiO.sub\$3	USPAT; US-PGPUB	2003/09/28 13:47
19	42	porous with thermal adj conductivity with silicon	USPAT; US-PGPUB	2003/09/28 13:32
20	12	porous with thermal adj conductivity with silicon with \$2oxide\$2	USPAT; US-PGPUB	2003/09/28 13:48
21	0	porous with heat adj conductivity with SiO.sub\$3	USPAT; US-PGPUB	2003/09/28 13:47
22	3	porous with heat adj conductivity with silicon with \$2oxide\$2	USPAT; US-PGPUB	2003/09/28 13:51
23	7	porous with thermal adj conductivity with silicon with oxide	USPAT; US-PGPUB	2003/09/28 13:53
24	789	porous with thermal adj conductivity	USPAT; US-PGPUB	2003/09/28 13:53
25	147	porous with thermal adj conductivity with layer	USPAT; US-PGPUB	2003/09/28 13:53
26	42	porous with thermal adj conductivity with silicon	USPAT; US-PGPUB	2003/09/28 13:54
27	27	porous with thermal adj conductivity with oxide	USPAT; US-PGPUB	2003/09/28 13:55
28	24	porous with thermal adj conductivity with silica	USPAT; US-PGPUB	2003/09/28 14:05
29	3937	laser with (crystal\$9 anneal\$3) with (polysilicon silicon)	USPAT; US-PGPUB	2003/09/28 14:07
30	7	(laser with (crystal\$9 anneal\$3) with (polysilicon silicon)) and aerogel	USPAT; US-PGPUB	2003/09/28 14:08
31	80862	(alumina aluminum adj \$2oxide) with (silica silicon adj \$2oxide)	USPAT; US-PGPUB	2003/09/28 14:09
32	533	(alumina aluminum adj \$2oxide) with (silica silicon adj \$2oxide) with doped	USPAT; US-PGPUB	2003/09/28 14:09
33	1332	(alumina aluminum adj \$2oxide) with (silica silicon adj \$2oxide) with alloy	USPAT; US-PGPUB	2003/09/28 14:10
34	43	(alumina aluminum adj \$2oxide) with (silica silicon adj \$2oxide) with alloy with strength	USPAT; US-PGPUB	2003/09/28 14:37
36	674871	(alumina aluminum adj \$2oxide) with (silica silicon adj \$2oxide) with alloy with porous strength	USPAT; US-PGPUB	2003/09/28 14:12
37	2	(alumina aluminum adj \$2oxide) with (silica silicon adj \$2oxide) with alloy with porous with strength	USPAT; US-PGPUB	2003/09/28 14:30
38	65	(alumina aluminum adj \$2oxide) with (silica silicon adj \$2oxide) with alloy with porous	USPAT; US-PGPUB	2003/09/28 14:30
35	65	(alumina aluminum adj \$2oxide) with (silica silicon adj \$2oxide) with alloy with porous	USPAT; US-PGPUB	2003/09/28 14:37
39	1230	(alumina aluminum adj \$2oxide) with (silica silicon adj \$2oxide) with strength	USPAT; US-PGPUB	2003/09/28 14:37
40	137	(alumina aluminum adj \$2oxide) with (silica silicon adj \$2oxide) with strength with increase	USPAT; US-PGPUB	2003/09/28 14:38
41	2	(alumina aluminum adj \$2oxide) with (silica silicon adj \$2oxide) with strength with increase with alloy	USPAT; US-PGPUB	2003/09/28 14:58
42	4	(alumina aluminum adj \$2oxide) with (silica silicon adj \$2oxide) with strength with increase with layer	USPAT; US-PGPUB	2003/09/28 14:40
43	23	(alumina aluminum adj \$2oxide) adj doped adj (silica silicon adj \$2oxide)	USPAT; US-PGPUB	2003/09/28 14:44
44	1	(alumina aluminum adj \$2oxide) with doped with (silica silicon adj \$2oxide) with strength	USPAT; US-PGPUB	2003/09/28 14:47
45	172980	porous (silica silicon adj \$2oxide) with (electron e) adj beam adj evaporation	USPAT; US-PGPUB	2003/09/28 14:48
46	0	porous adj (silica silicon adj \$2oxide) with (electron e) adj beam adj evaporation	USPAT; US-PGPUB	2003/09/28 14:48

47	1	porous with (silica silicon adj \$2oxide) with (electron e) adj beam adj evaporation	USPAT; US-PGPUB	2003/09/28 14:49
48	179	(silica silicon adj \$2oxide) with (electron e) adj beam adj evaporation	USPAT; US-PGPUB	2003/09/28 14:49
49	15	(porous) with (electron e) adj beam adj evaporation	USPAT; US-PGPUB	2003/09/28 14:49
66	674	(alumina aluminum adj \$2oxide) with (silica silicon adj \$2oxide) with aerogel	USPAT; US-PGPUB	2003/09/28 14:58
67	30	(alumina aluminum adj \$2oxide) with (silica silicon adj \$2oxide) with aerogel and (electron e) adj beam adj evaporation	USPAT; US-PGPUB	2003/09/28 14:58
-	1998	(427/554,557,559,551,552,595,596).CCLS.	USPAT; US-PGPUB	2003/09/24 15:41
-	79	((427/554,557,559,551,552,595,596).CCLS.) and polysilicon	USPAT; US-PGPUB	2003/09/24 15:41
-	238	((427/554,557,559,551,552,595,596).CCLS.) and (polysilicon or poly adj silicon or (crystal\$5 anneal\$5) with silicon)	USPAT; US-PGPUB	2003/09/24 15:57
-	23	((427/554,557,559,551,552,595,596).CCLS.) and (polysilicon or poly adj silicon or (crystal\$5 anneal\$5) with silicon)) and porous	USPAT; US-PGPUB	2003/09/24 15:42
-	1866	laser with anneal\$3 same (polysilicon or poly adj silicon or (crystal\$5) with silicon)	USPAT; US-PGPUB	2003/09/24 15:49
-	2166	laser with anneal\$3 with (polysilicon or poly adj silicon or silicon)	USPAT; US-PGPUB	2003/09/28 14:06
-	8	(laser with anneal\$3 with (polysilicon or poly adj silicon or silicon)) and porous with buffer	USPAT; US-PGPUB	2003/09/24 15:49
-	1942	(e or electron) adj beam with evap\$9 and (polysilicon or poly adj silicon or (crystal\$5 anneal\$5) with silicon)	USPAT; US-PGPUB	2003/09/24 15:52
-	16	(e or electron) adj beam with evap\$9 with buffer and (polysilicon or poly adj silicon or (crystal\$5 anneal\$5) with silicon)	USPAT; US-PGPUB	2003/09/24 15:56
-	1315	porous with (buffer barrier) and (polysilicon or silicon)	USPAT; US-PGPUB	2003/09/24 15:58
-	311	(porous with (buffer barrier) and (polysilicon or silicon)) and laser	USPAT; US-PGPUB	2003/09/24 15:58
-	80	(porous with (buffer barrier) and (polysilicon or silicon)) and laser with (crystal\$9 or anneal\$6)	USPAT; US-PGPUB	2003/09/24 15:59
-	61	((porous with (buffer barrier) and (polysilicon or silicon)) and laser with (crystal\$9 or anneal\$6)) and conductivity	USPAT; US-PGPUB	2003/09/24 16:29
-	19	((porous with (buffer barrier) and (polysilicon or silicon)) and laser with (crystal\$9 or anneal\$6)) and conductivity) not (semiconductor adj energy).as.	USPAT; US-PGPUB	2003/09/24 16:29
-	25	((porous with (buffer barrier) and (polysilicon or silicon)) and laser with (crystal\$9 or anneal\$6)) not (semiconductor adj energy).as.	USPAT; US-PGPUB	2003/09/24 16:29
-	6	((porous with (buffer barrier) and (polysilicon or silicon)) and laser with (crystal\$9 or anneal\$6)) not (semiconductor adj energy).as.) not (((porous with (buffer barrier) and (polysilicon or silicon)) and laser with (crystal\$9 or anneal\$6)) and conductivity) not (semiconductor adj energy).as.)	USPAT; US-PGPUB	2003/09/24 16:31
-	657	(427/585,588).CCLS.	USPAT; US-PGPUB	2003/09/24 16:33
-	81	((427/585,588).CCLS.) and porous	USPAT; US-PGPUB	2003/09/24 16:33
-	4	((427/585,588).CCLS.) and porous with (buffer barrier)	USPAT; US-PGPUB	2003/09/24 16:35
-	0	427/566-568	USPAT; US-PGPUB	2003/09/24 16:35



-	9	((polycrystalline adj silicon polysilicon or (crystal\$8 with (silicon Si)))) with laser) and (thermal heat) adj conductivity with (buffer barrier) with layer	USPAT; US-PGPUB	2003/09/25 16:09
-	11	((polycrystalline adj silicon polysilicon or (crystal\$8 with (silicon Si)))) with laser) and (thermal heat) adj conductivity with (buffer barrier)	USPAT; US-PGPUB	2003/09/25 16:13
-	52	((polycrystalline adj silicon polysilicon or (crystal\$8 with (silicon Si)))) with laser) and low adj (thermal heat) adj conductivity	USPAT; US-PGPUB	2003/09/25 16:13
-	135	((polycrystalline adj silicon polysilicon or (crystal\$8 with (silicon Si)))) with laser) and low\$5 with (thermal heat) adj conductivity	USPAT; US-PGPUB	2003/09/25 16:13
-	54	((polycrystalline adj silicon polysilicon or (crystal\$8 with (silicon Si)))) with laser) and low\$5 with (thermal heat) adj conductivity with layer	USPAT; US-PGPUB	2003/09/25 16:14